



DCR2630C28

Phase Control Thyristor

Replaces DS5803-4 DS5803-5 August 2023 (LN42747)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages VDRM and VRRM (V)	Conditions
DCR2630C28 DCR2630C26 DCR2630C24	2800 2600 2400	Tvj = -40°C to 125°C, IDRM = IRRM = 200mA, VDRM, VRRM tp = 10ms VDSM & VRSM = VDRM & VRRM + 100V respectively

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR2630C28

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

\mathbf{V}_{DRM}	2800V
I _{T(AV)}	2630A
Ітѕм	35300A
dV/dt*	1500V/µs
dl/dt	300A/μs

^{*} Higher dV/dt selections are available on request

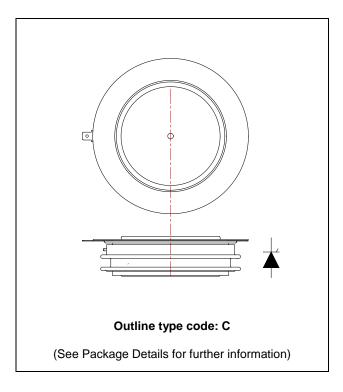


Fig. 1 Package outline

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CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions		Units
Double Side Cooled				
IT(AV)	Mean on-state current	Half wave resistive load	2630	А
IT(RMS)	RMS value	-	4130	А
lτ	Continuous (direct) on-state current	-	3940	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, Tcase = 125°C	35.3	kA
l²t	I2t for fusing	V _R = 0	6.23	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Condition	Test Conditions		Max.	Units
		Double side cooled	DC	-	10.1	°C/kW
Rth(j-c)	Thermal resistance - junction to case	Cingle side socied	Anode DC	-	17.6	°C/kW
		Single side cooled	Cathode DC	-	23.9	°C/kW
D	The annual manifestation and the best similar	Clamping force 37kN	Double side	-	2.5	°C/kW
Kth(c-h)	Rth(c-h) Thermal resistance - case to heatsink (with mounting comp		Single side	-	5.0	°C/kW
Tvj	Virtual junction temperature	Blocking Vdrm / Vrrm		-	125	°C
Tstg	Storage temperature range			-55	125	°C
Fm	Clamping force			33	41	kN

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DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Condition	ıs	Min.	Max.	Units
IRRM/IDRM	Peak reverse and off-state current	At Vrrm/Vdrm, Tcase = 125°C		-	200	mA
Vтм	Instantaneous forward voltage	At 4000A peak, T _j = 125°C		1.40	1.65	V
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, g	ate open	-	1500	V/µs
dl/dt	Rate of rise of on-state current	From 67% VDRM to 2x IT(AV)	Repetitive 50Hz	-	150	A/µs
di/dt	Nate of fise of off-state current	Gate source 30V, 10Ω tr < 0.5μs, Tj = 125°C	Non-repetitive	-	300	A/µs
V T(TO)	Threshold voltage - Low level	500A to 2300A at Tcase = 125°C		-	0.83	V
V 1(10)	Threshold voltage - High level	2300A to 7000A at Tcase = 125°C		-	0.97	\
	On-state slope resistance - Low level	500A to 2300A at Tcase = 125°C		-	0.23	mΩ
ľΤ	On-state slope resistance - High level	2300A to 7000A at Tcase = 1	25°C	-	0.17	mΩ
tgd	Delay time	$V_D = 67\% \ V_{DRM}$, gate source 30V, 10Ω tr = 0.5 μ s, $T_j = 25$ °C		-	3	μs
tq	Turn-off time	T _j = 125°C, V _R = 200V, dI/dt = 1A/μs, dV _{DR} /dt = 20V/μs linear		100	250	μs
Qs	Stored charge	Iτ = 2000A, Tj = 125°C, dl/dt = 1A/μs		450	2000	μC
IL	Latching current	Tj = 25°C, VD = 5V		-	3	А
lн	Holding current	Tj = 25°C, Rg-κ = ∞, Iτм = 50	0Α, Iτ = 5Α	-	300	mA

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GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V GT	Gate trigger voltage	VDRM = 5V, Tcase = 25°C	1.5	V
V _{GD}	Gate non-trigger voltage	At 50% VDRM, Tcase = 125°C	0.4	V
lgт	Gate trigger current	VDRM = 5V, Tcase = 25°C	250	mA
IGD	Gate non-trigger current	At 50% VDRM, Tcase = 125°C	10	mA

CURVES

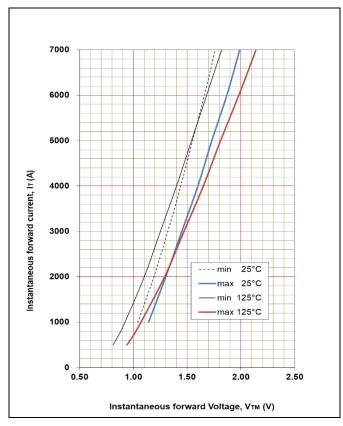


Fig. 2 Maximum & minimum on-state characteristics

VTM EQUATION

 $V_{TM} = A + B.ln(I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.533109

B = 0.039168

C = 0.000126

D = 0.004483

These values are valid for $T_j = 125^{\circ}C$ for I_{T} 500A to 7000A

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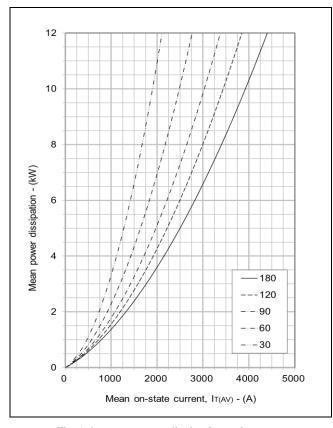


Fig. 3 On-state power dissipation - sine wave

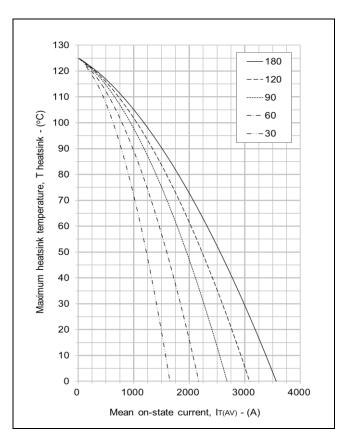


Fig. 5 Maximum permissible heatsink temperature, double side cooled - sine wave

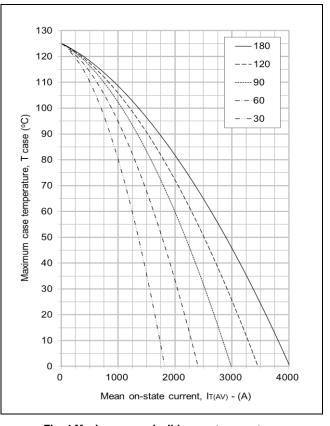


Fig. 4 Maximum permissible case temperature, double side cooled - sine wave

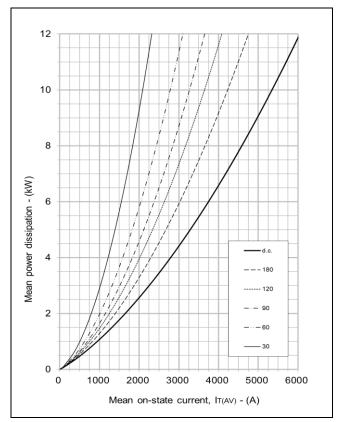


Fig. 6 On-state power dissipation - rectangular wave

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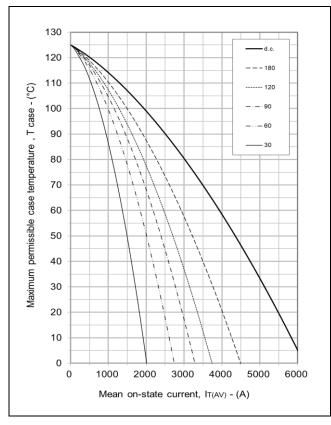
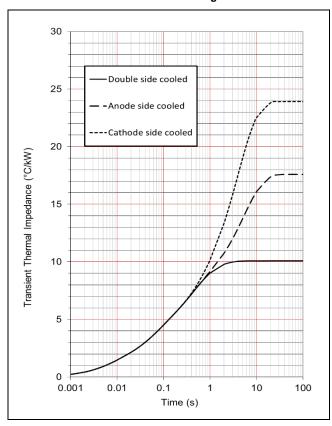


Fig. 7 Maximum permissible case temperature, double side cooled - rectangular wave



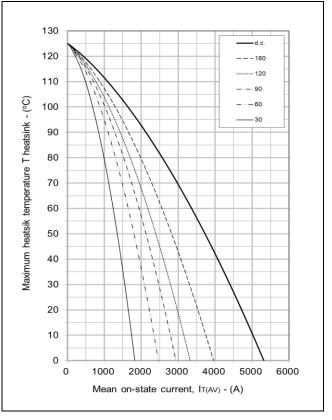


Fig. 8 Maximum permissible heatsink temperature, double side cooled - rectangular wave

		1	2	3	4
Double side	Ri(°C/kW)	1.104	2.576	4.510	1.901
cooled	Ti(s)	0.006	0.052	0.382	1.060
Anode side cooled	Ri(°C/kW)	1.098	2.457	4.047	9.999
	Ti(s)	0.006	0.050	0.313	5.270
Cathode side	Ri(°C/kW)	1.152	2.893	2.406	17.479
cooled	Ti(s)	0.006	0.058	0.378	3.970

$$Z_{th} = \sum_{i=1}^{i=4} R_i \cdot \left(1 - \exp\left(-\frac{T}{T_i}\right)\right)$$

 $\Delta R_{\text{th(j-c)}}$ Conduction

Tables show the increments of thermal resistance R $_{\text{th(j-c)}}$ when the device operates at conduction angles other than d.c.

Double side cooling						
	ΔZ_{th} ((z)				
θ°	sine.	rect.				
180	1.95	1.26				
120	2.32	1.89				
90	2.74	2.27				
60	3.14	2.70				
30	3.46	3.19				
15	3.61	3 47				

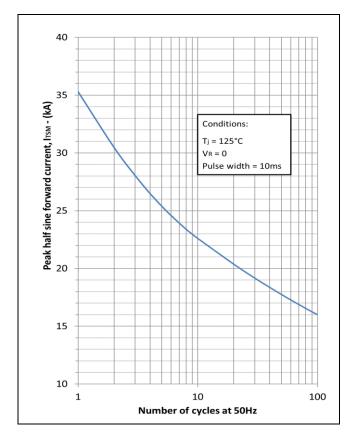
,	Anode Side Cooling				Anode Side Cooling Cathode Sided Cooling					d Cooling
	$\Delta Z_{th}(z)$		ΔZ_{th} (z)				ΔZ_t	_h (z)		
θ°	sine.	rect.		θ°	sine.	rect.				
180	1.95	1.26		180	1.95	1.26				
120	2.32	1.89		120	2.31	1.88				
90	2.74	2.27		90	2.72	2.26				
60	3.14	2.70		60	3.12	2.68				
30	3.46	3.19		30	3.43	3.17				
15	3.62	3.47		15	3 58	3 ///				

Cathode Sided Cooling				
	ΔZ_{th} (z)			
θ°	sine.	rect.		
180	1.95	1.26		
120	2.31	1.88		
90	2.72	2.26		
60	3.12	2.68		
30	3.43	3.17		
15	3 58	3.44		

Fig. 9 Maximum (limit) transient thermal impedance - junction to case (degC/kW)

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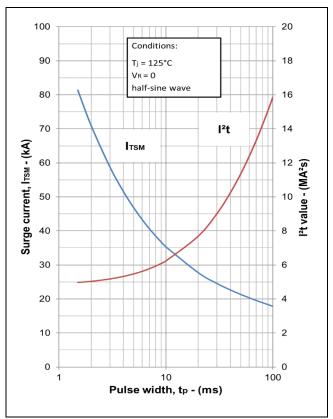


Fig. 10 Multi-cycle surge current

Fig. 11 Single-cycle surge current

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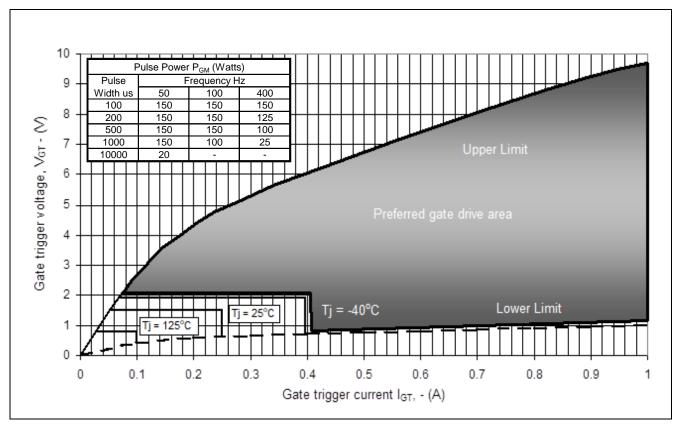


Fig. 14 Gate characteristics

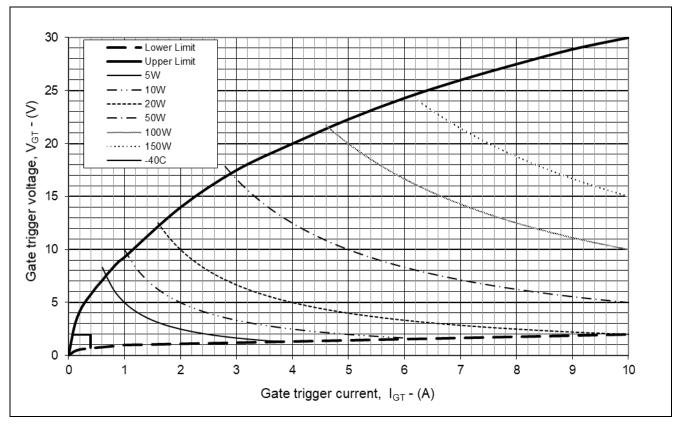


Fig. 15 Gate characteristics

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PACKAGE DETAILS

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE

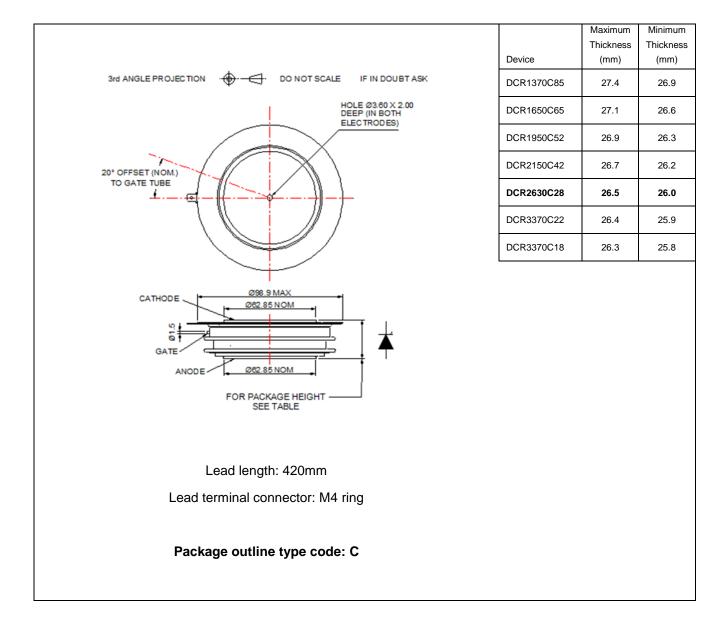


Fig. 16 Package outline

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